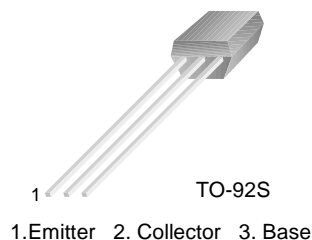


# FJNS3208R

FJNS3208R

## Switching Application (Bias Resistor Built In)

- Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor ( $R_1=47K\Omega$ ,  $R_2=22K\Omega$ )
- Complement to FJNS4208R

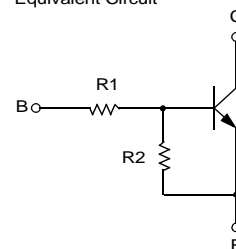


## NPN Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	50	V
$V_{CEO}$	Collector-Emitter Voltage	50	V
$V_{EBO}$	Emitter-Base Voltage	10	V
$I_C$	Collector Current	100	mA
$P_C$	Collector Power Dissipation	300	mW
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Equivalent Circuit



### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C=10\mu\text{A}$ , $I_E=0$	50			V
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C=100\mu\text{A}$ , $I_B=0$	50			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=40\text{V}$ , $I_E=0$			0.1	$\mu\text{A}$
$h_{FE}$	DC Current Gain	$V_{CE}=5\text{V}$ , $I_C=5\text{mA}$	56			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=10\text{mA}$ , $I_B=0.5\text{mA}$			0.3	V
$f_T$	Current Gain Bandwidth Product	$I_C=10\text{mA}$ , $I_B=0.5\text{mA}$		250		MHz
$C_{ob}$	Output Capacitance	$V_{CB}=10\text{V}$ , $I_E=0$ $f=1.0\text{MHz}$		3.7		pF
$V_{I(off)}$	Input Off Voltage	$V_{CE}=5\text{V}$ , $I_C=100\mu\text{A}$	0.8			V
$V_{I(on)}$	Input On Voltage	$V_{CE}=0.3\text{V}$ , $I_C=2\text{mA}$			4	V
$R_1$	Input Resistor		32	47	62	$K\Omega$
$R_1/R_2$	Resistor Ratio		1.9	2.1	2.4	

# Typical Characteristics

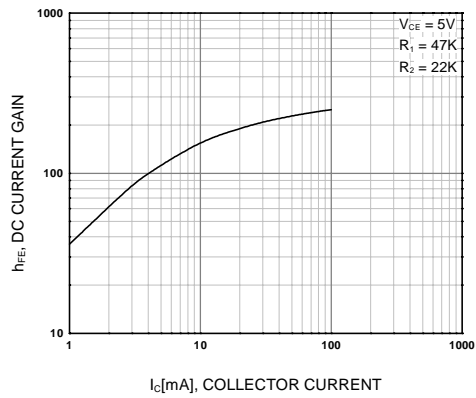


Figure 1. DC current Gain

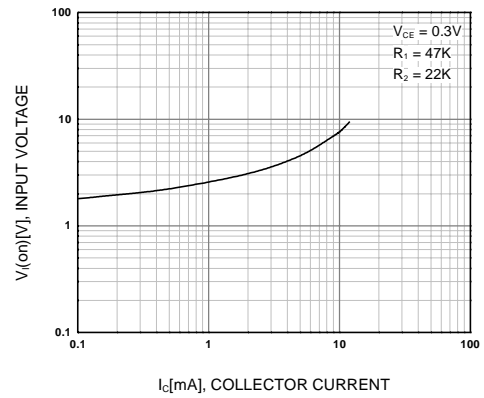


Figure 2. Input On Voltage

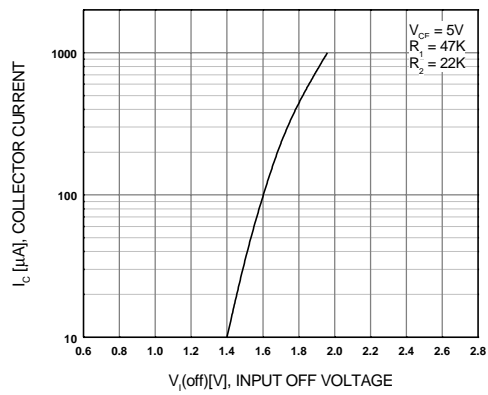


Figure 3. Input Off Voltage

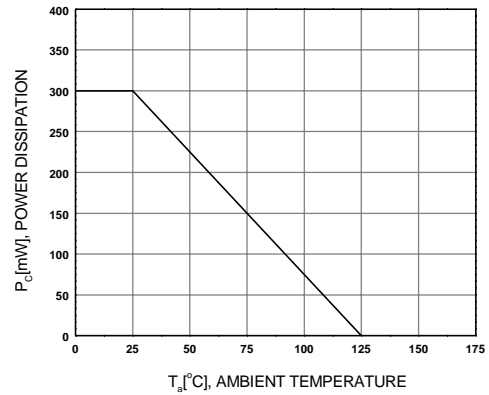
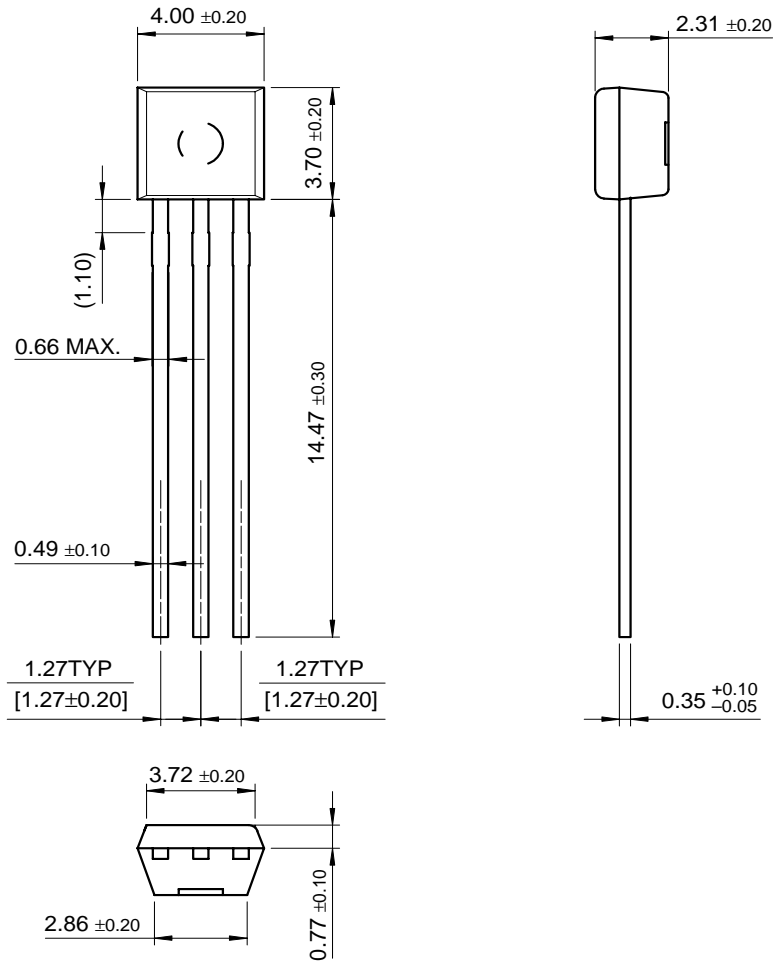


Figure 4. Power Derating

# Package Dimensions

## TO-92S



Dimensions in Millimeters

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Programmable Active Droop <sup>™</sup>		OPTOPLANAR <sup>™</sup>	SMART START <sup>™</sup>	

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